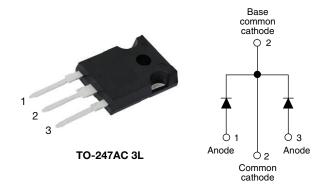


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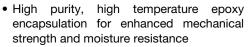
High Performance Schottky Rectifier, 2 x 20 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 20 A					
V _R	45 V				
V _F at I _F	0.56 V				
I _{RM} max.	110 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	20 mJ				
Package	TO-247AC 3L				
Circuit configuration	Common cathode				

FEATURES

- 150 °C T_J operation
- · Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR4045WT... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	40	^			
I _{FRM}	T _C = 125 °C (per leg)	40	A			
V _{RRM}		45	V			
I _{FSM}	$t_p = 5 \mu s sine$	1020	Α			
V _F	20 A _{pk} , T _J = 125 °C	0.56	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-MBR4045WT-N3	UNITS
Maximum DC reverse voltage	V_R	45	V
Maximum working peak reverse voltage	V_{RWM}	45	

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average	per leg		20	T 105 °C 50 °C duty avala reatenavilar waveferm		T 105 °C 50 °C duty avala vastas avalav vastas av		20	
forward current	per device	I _{F(AV)}	1° = 125 °C, 50 % duty cycle,	T _C = 125 °C, 50 % duty cycle, rectangular waveform					
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 125 °C		40	Α			
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7		I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1020				
			10 ms sine or 6 ms rect. pulse	V _{RRM} applied	265				
Non-repetitive avalanche energy per leg E		E _{AS}	$T_J = 25$ °C, $I_{AS} = 3$ A, $L = 4.40$ mH		20	mJ			
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		3	Α			



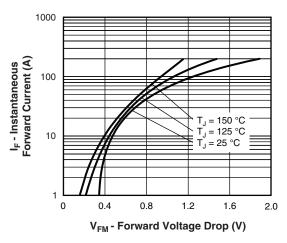
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T _{.1} = 25 °C	0.59	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.78	
Maximum forward voltage drop	VFM (1)	20 A	T _{.1} = 125 °C	0.56	
		40 A	1J = 125 C	0.72	
	I _{RM} ⁽¹⁾	T _J = 25 °C		1.75	mA
Maximum instantaneous reverse current		T _J = 100 °C	Rated DC voltage	50	
		T _J = 125 °C		110	
Threshold voltage	V _{F(TO)}	T. – T. movimum		0.29	V
Forward slope resistance	r _t	$T_J = T_J$ maximum		10.3	mΩ
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		900	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane		7.5	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-55 to 150	°C	
Maximum storage temperature range	T _{Stg}		-55 to 175	C	
Maximum thermal resistance, junction to case per package	R _{thJC}	DC operation	1.4	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.7	C/VV	
Approximate weight			6	g	
Approximate weight			0.21	oz.	
Mounting torque minimum			6 (5)	kgf · cm	
Mounting torque maximum			12 (10)	(lbf · in)	
Device marking		Case style TO-247AC 3L	MBR4	045WT	







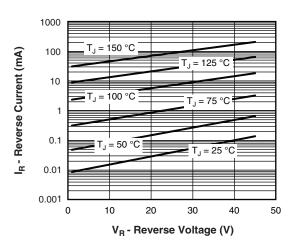


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

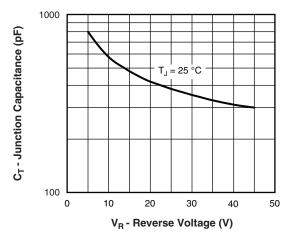


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

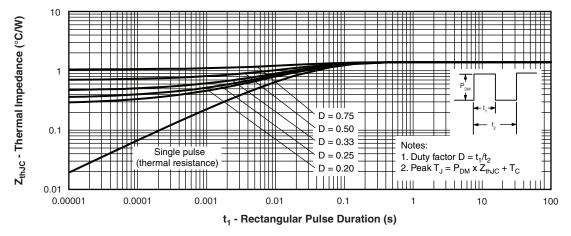


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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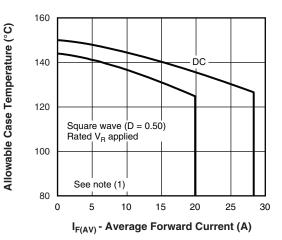


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

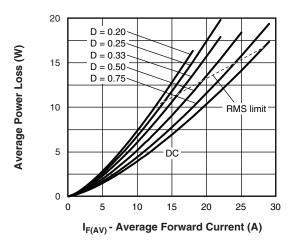


Fig. 6 - Forward Power Loss Characteristics

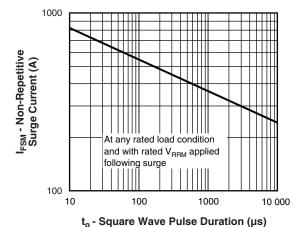


Fig. 7 - Maximum Non-Repetitive Surge Current

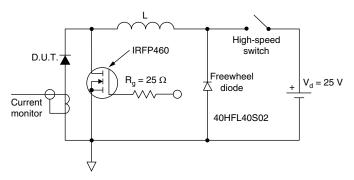


Fig. 8 - Unclamped Inductive Test Circuit

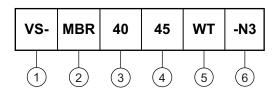
Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = <math>I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = <math>V_{R1} \times I_{R1} (1 - D)$; $I_{R1} = rated V_{R1} (1 - D)$; $I_{R2} = rated V_{R3} (1 - D)$; $I_{R3} = rated V_{R3} (1 - D)$;



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky MBR series

- Current rating (40 = 40 A)

- Voltage rating (45 = 45 V)

5 - Circuit configuration:

Center tap (dual) TO-247

6 - Environmental digit

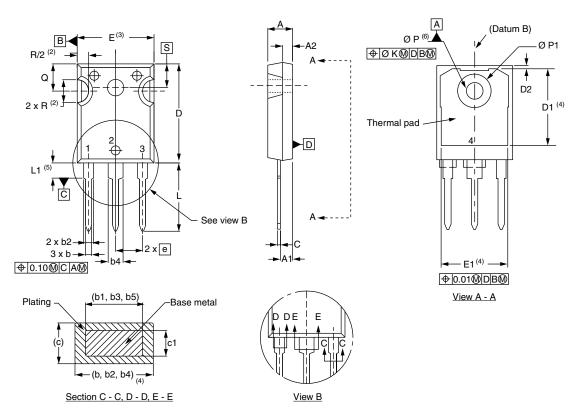
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-MBR4045WT-N3	25	500	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96138</u>				
Part marking information	www.vishay.com/doc?95007			
SPICE model	www.vishay.com/doc?95297			

TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STINIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254)10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension Q



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